NSN 5961-01-463-9702

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-463-9702 **Inclosure Material:** Plastic **Overall Length:** 2.185 inches **Terminal Length:** 0.185 inches **Overall Diameter:** 0.180 inches **End Application:** Rsippple/ifscm30003 **Mounting Facility Quantity: Mounting Method: Terminal Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 800.0 working peak reverse voltage and 1.2 on voltage, forward voltage drop, dc **Current Rating Per Characteristic:** 150.00 amperes source cutoff current preset and 25.00 amperes forward current, average outside diameter **Maximum Operating Tempurature Per Measurement Point:** -65.0 degrees celsius case and 200.0 degrees celsius case **Test Data Document:** 30003-13217882-01 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 2 uninsulated wire lead **Specification Data:** 30003-mil-s-19500/420 government specification Shelf Life: N/a **Unit Of Measure: Demilitarization:**